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# GEOMETRIC IONIC DIODE: THE ROLE OF CONFINEMENT

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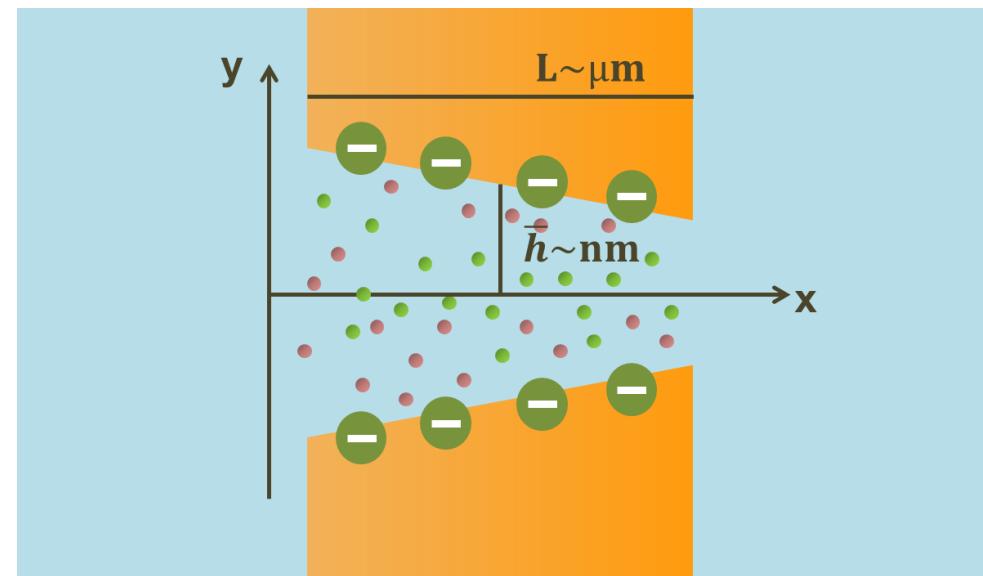
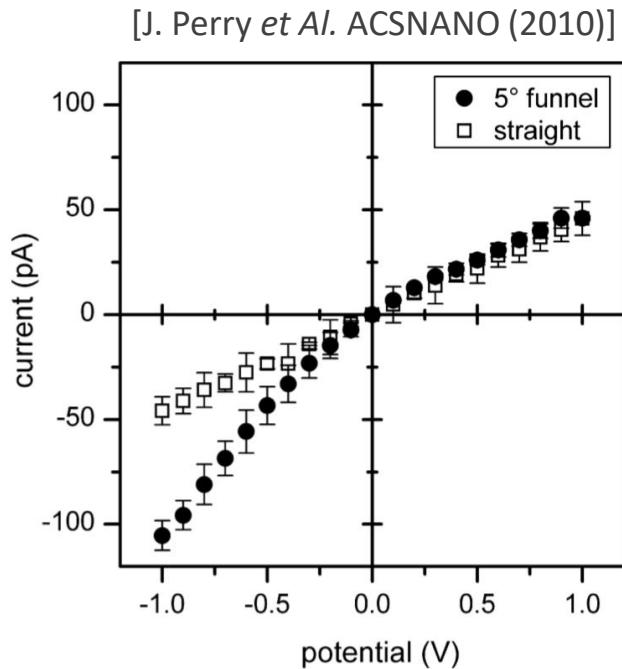


UNIVERSITAT DE  
BARCELONA

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# IONIC CURRENT RECTIFICATION

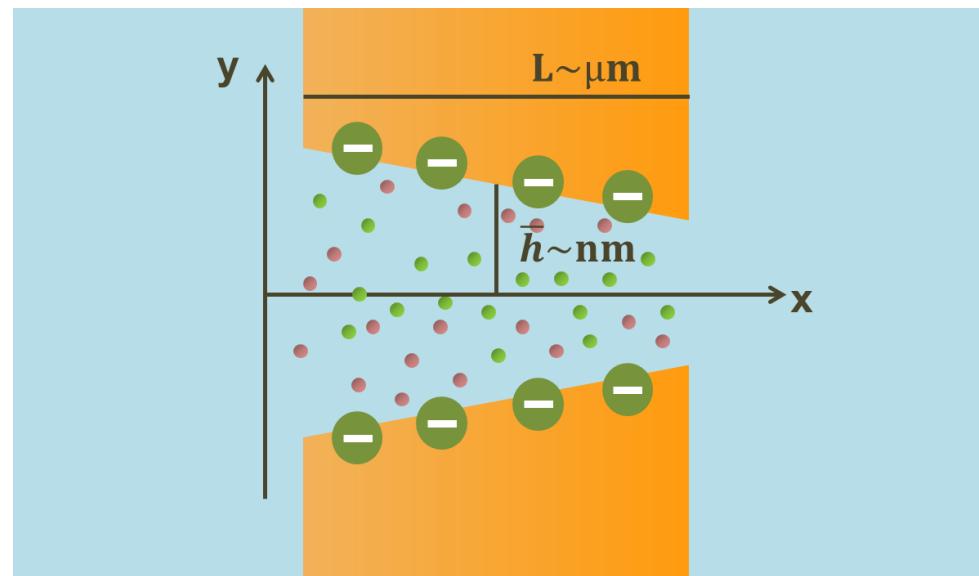
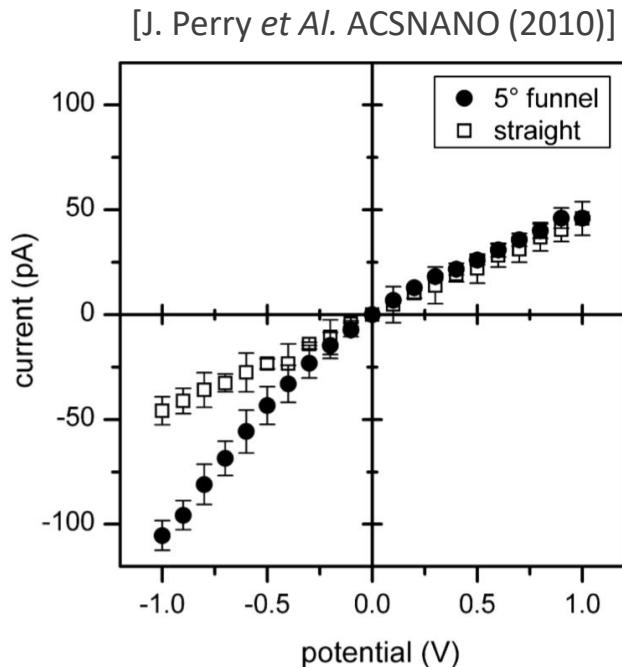
**Nonlinear** current response under voltage reversal



PREFERENTIAL DIRECTION OF MOTION IN THE ABSENCE OF NET FORCING

# IONIC CURRENT RECTIFICATION

**Nonlinear** current response under voltage reversal

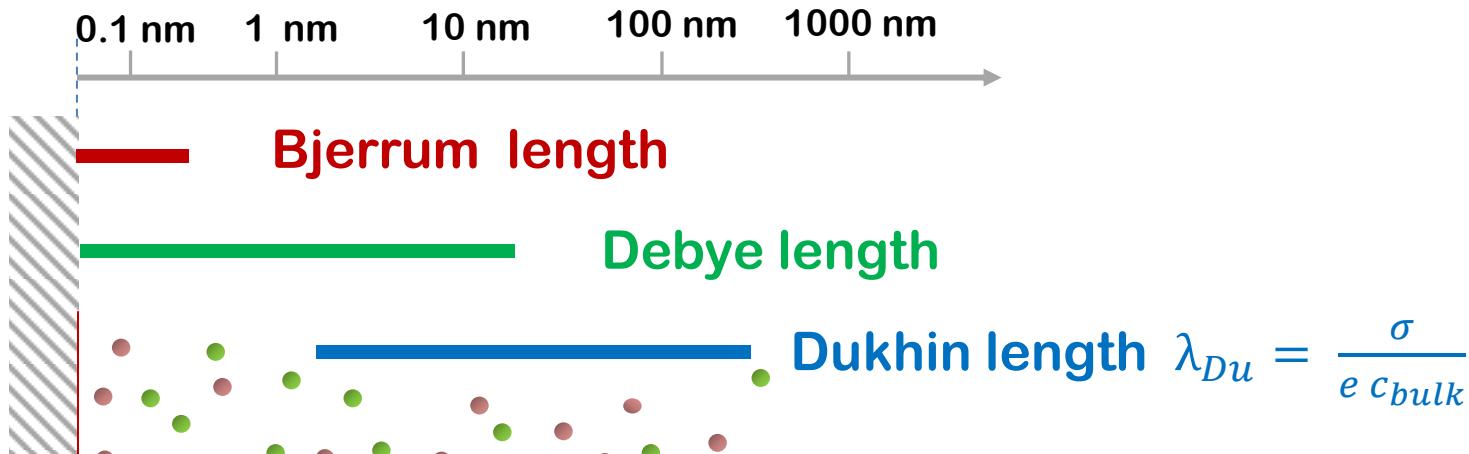


Building blocks:

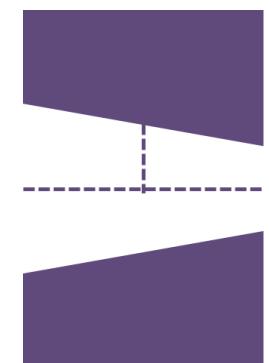
{  
Symmetry breaking  
Surface interactions

# IMPORTANT LENGTHS INTO PLAY

*Electrostatic lengths...*



*...vs geometric lengths*



Partial Debye overlap

$$\frac{\lambda_D}{\bar{h}} \sim 1$$

Quasi 1D system

$$\bar{h} \ll L$$

# FICK-JACOBS APPROACH

[M. H. Jacobs (1967) , R. Zwanzig (1992)]

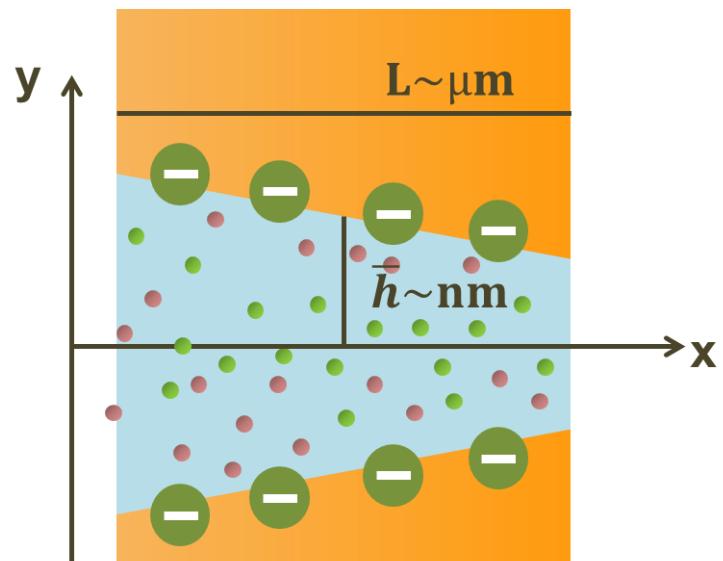
Nernst-Planck equation:

$$\partial_t c_{\pm} + \nabla \cdot \vec{J} = 0$$

$$\vec{J} = \mp c_{\pm}(x, y, t) \nabla V(x, y) - \nabla c_{\pm}(x, y, t)$$

Assuming separation of scales:

$$d_x h(x) = \epsilon \ll 1 \Leftrightarrow j_y \ll j_x$$



Channel profile:

$$h(x) = \bar{h} + \epsilon \frac{L}{2} - \epsilon x$$

Perturbative expansion in the geometrical parameter  $\epsilon$

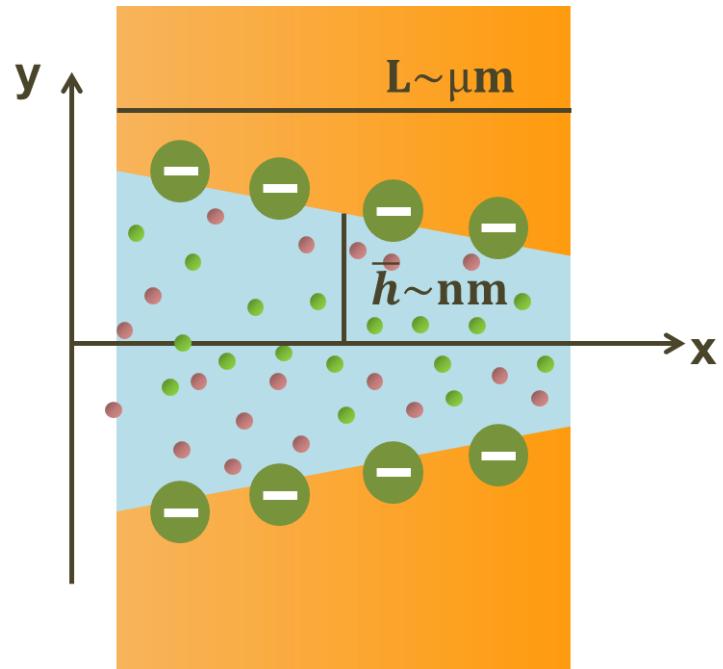
[S. Martens *et al* PRE (2011)]

# FICK-JACOBS APPROACH

Nernst-Planck equation:

$$\partial_t c_{\pm} + \nabla \cdot \vec{J} = 0$$

$$\vec{J} = \mp c_{\pm}(x, y, t) \nabla V(x, y) - \nabla c_{\pm}(x, y, t)$$



Integrating in the transverse direction:

**Marginal concentration:**  $c_{\pm}(x) = \int_{-h(x)}^{h(x)} c_{\pm}(x, y) dy$

**Ansatz:**  $c_{\pm}(x, y) = \frac{e^{\mp V(x, y)}}{e^{-\beta A_{\pm}(x)}} c_{\pm}(x)$

conditional density

**Effective free energy:**

$$e^{-\beta A_{\pm}(x)} = \int_{-h(x)}^{h(x)} e^{\mp V(x, y)} dy$$

# GOVERNING EQUATIONS

**Fick-Jacobs equation:**  $-J_{\pm} = c_{\pm}(x) \frac{d}{dx} \beta A_{\pm}(x) + \frac{d}{dx} c_{\pm}(x)$

**Poisson equation:**  $\partial_y^2 V = -\frac{q(x, y)}{\varepsilon}$

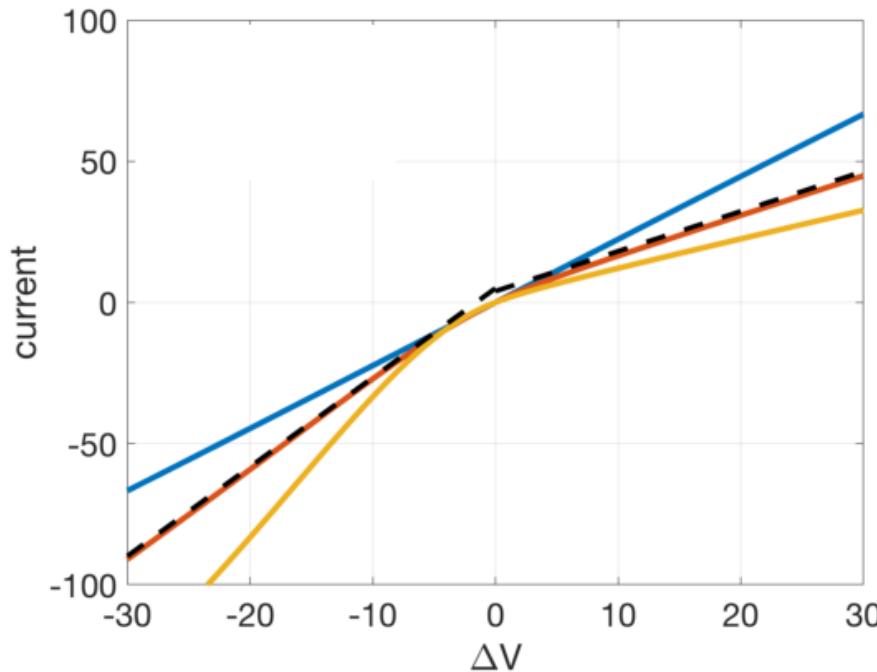
Solving for:

- Small potential variation  $\delta V \ll 1$
- Continuity in the chemical potential at the boundaries

$$\mu_{\pm}(x) = \log c_{\pm}(x) + \beta A_{\pm}(x)$$

# IONIC CURRENT RECTIFICATION

IV characteristics



- Rectification increasing with the channel corrugation
- Saturation to **limiting conductances** for high field

# IN THE LIMIT OF STRONG OVERLAP

*In equilibrium:*

**Non-uniform Donnan potential:**

$$V(x) = \frac{1}{2} \log \left[ \frac{-Du + \sqrt{Du^2 + h(x)^2}}{+Du + \sqrt{Du^2 + h(x)^2}} \right]$$

*Out of equilibrium:*  $\left\{ \begin{array}{l} J_{mass} = -\partial_x c_{tot}(x) + \cancel{c_{tot}(x)\partial_x \log 2h(x)} - 2 Du \partial_x V(x) \\ I_e = -c_{tot}(x)\partial_x V(x) + 2 Du \partial_x \log 2h(x) \end{array} \right.$

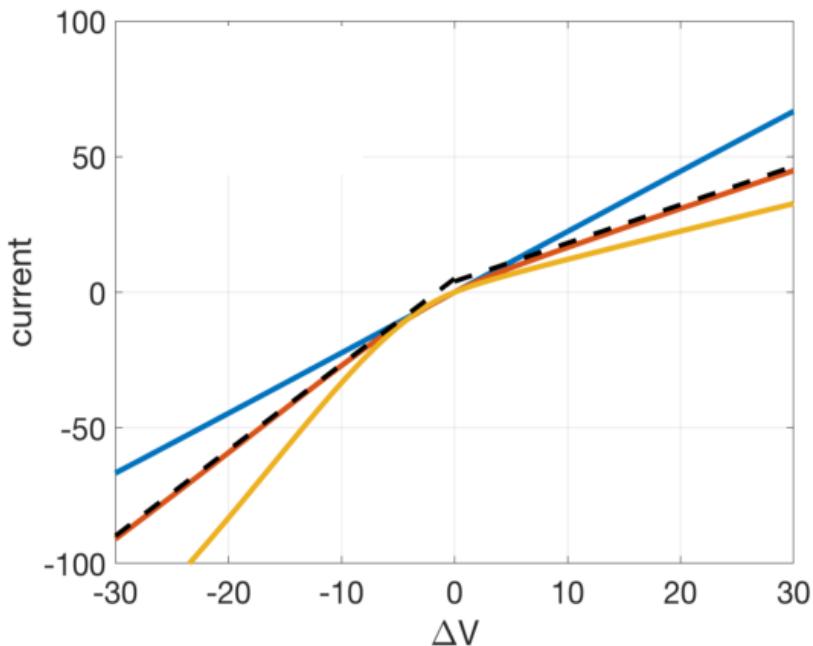
Limit  $\Delta V \rightarrow \infty$  Neglecting the diffusive contribution to mass flux

$$G_{\pm\infty} = \lim_{\Delta V \rightarrow \pm\infty} c_{tot}$$

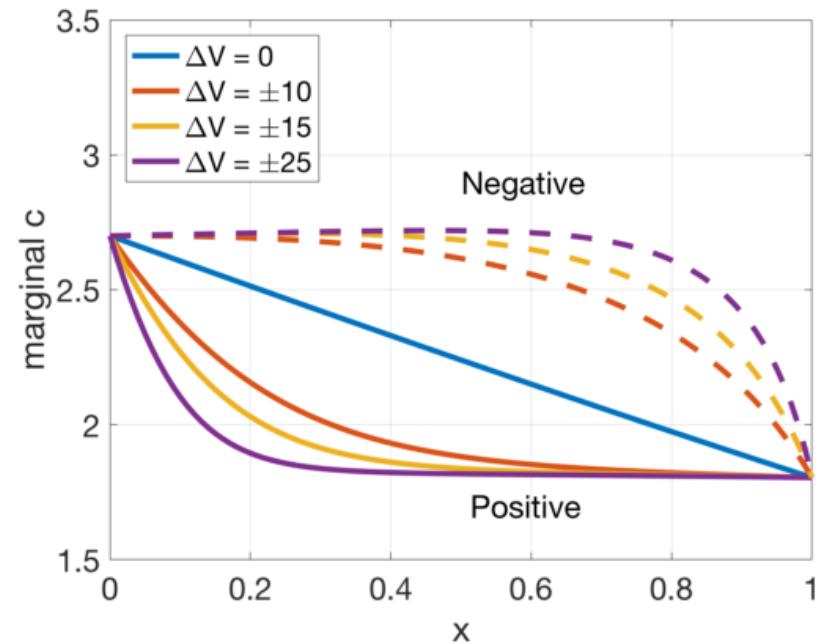
SATURATION OF THE MARGINAL CONCENTRATION

# IONIC CURRENT RECTIFICATION

IV characteristics

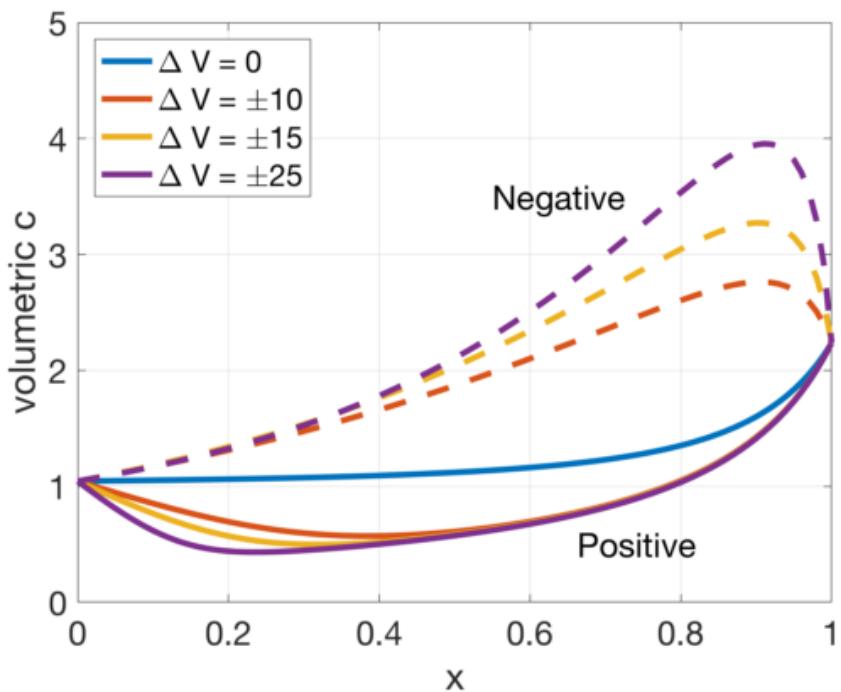


Saturation of the marginal concentration



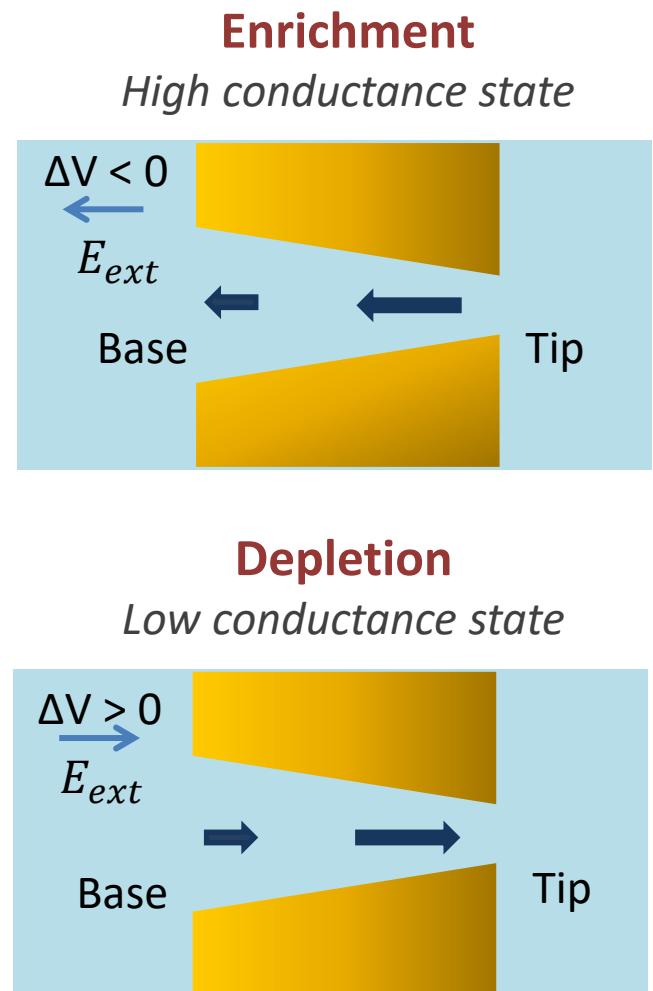
Analytical prediction for limiting conductances in  
the limit of strong overlap

# ENRICHMENT-DEPLETION

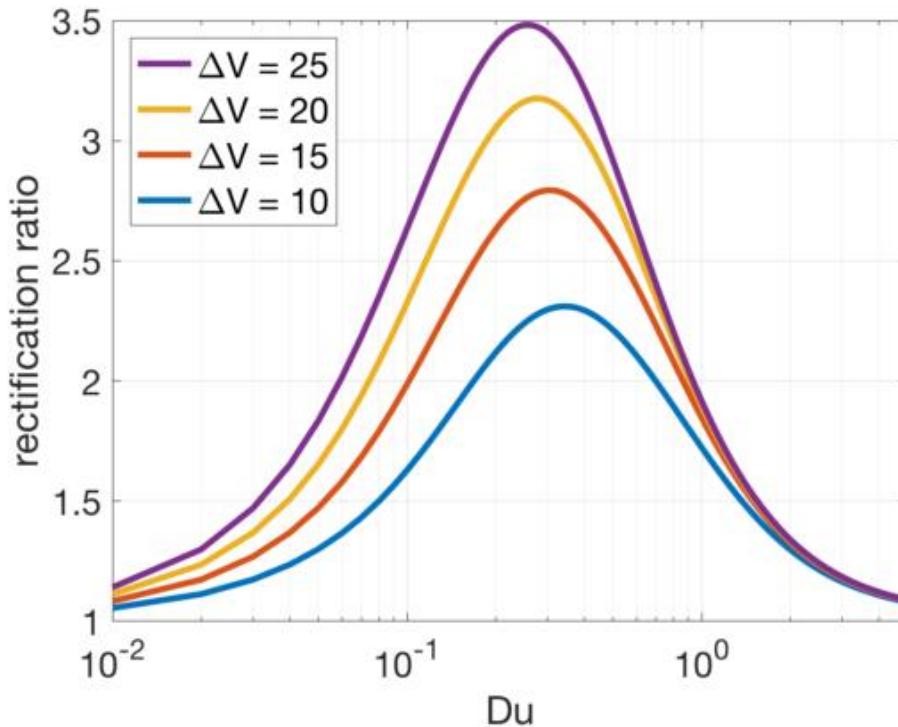


Asymmetric selectivities  
between tip and base

[Woermann Phys. Chem. Chem. Phys (2003)]



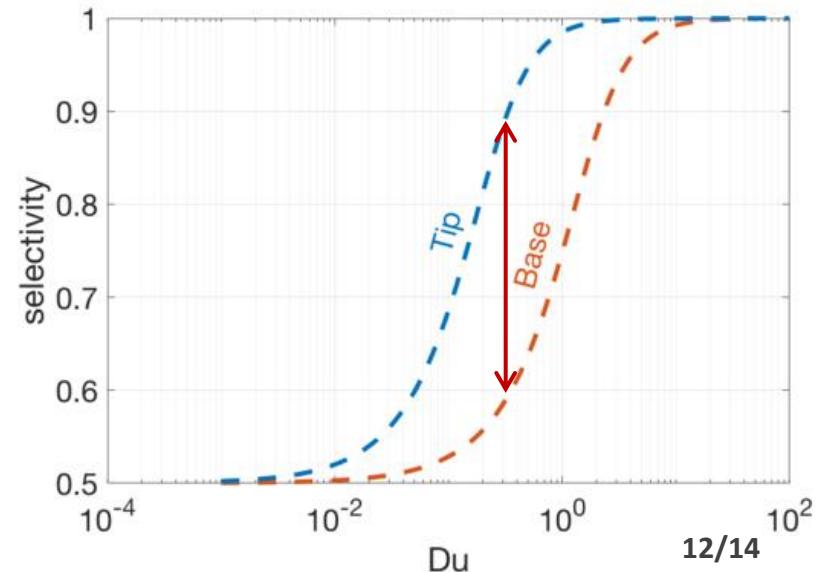
# THE IMPORTANCE OF DUKHIN NUMBER



Dukhin controls the asymmetry in selectivity

Maximum of rectification  
for  $D_u \sim 1$

$$\text{selectivity: } \frac{c_+}{c_+ + c_-}$$

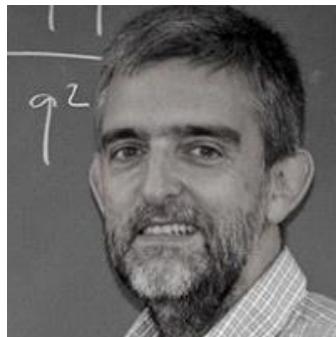


# CONCLUSION AND PERSPECTIVES

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- A general framework capturing rectification property
  - Consistent with the enrichment/depletion mechanism
  - Rectification controlled by the **Dukhin length** rather than the Debye length
  - Competition between bulk and surface... more to explore!
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# ACKNOWLEDGEMENT



Ignacio Pagonabarraga



Anthony Poggioli



# GOVERNING EQUATIONS

$$\left\{ \begin{array}{l} c_{\pm}(x) = \frac{1}{2} e^{\pm \frac{\Delta V}{2} - \beta A_{\pm}(x)} - J_{\pm} e^{-\beta A_{\pm}(x)} \int_0^x dx' e^{+\beta A_{\pm}(x')} \\ V(x, y) = - \frac{Du(x)}{\lambda_D(x)} \frac{\cosh\left(\frac{y}{\lambda_D(x)}\right)}{\sinh\left(\frac{h(x)}{\lambda_D(x)}\right)} + \frac{[c_+(x) - c_-(x)]}{[c_+(x) + c_-(x)]} + \langle V \rangle(x) \end{array} \right.$$

Debye-Hückel like potential
Local electroneutrality
Cross-section averaged potential

**Local Debye length:**

$$\lambda_D(x) = \frac{\lambda_D}{\sqrt{c_+(x) + c_-(x)}}$$

**Local Dukhin number:**

$$Du(x) = \frac{Du}{c_+(x) + c_-(x)}$$

Numerical solution of coupled integral equations